

٢٠ / Descriptions

Silicon NPN transistor in a SOT-323 Plastic Package.

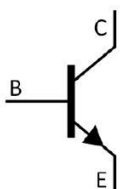
• È / Features

High current, low voltage complementary pair with BC807W.

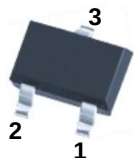
٧ ٤ / Applications

General purpose switching and amplification.

٧ ٥ ã = ε / Equivalent Circuit



ã ١ ٥~ / Pinning



PIN1 Emitter PIN 2 Base PIN 3 Collector

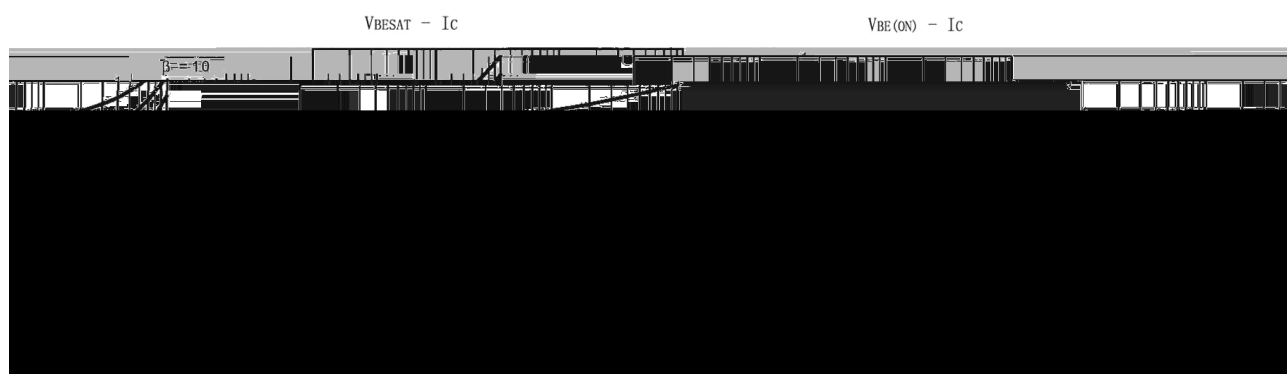
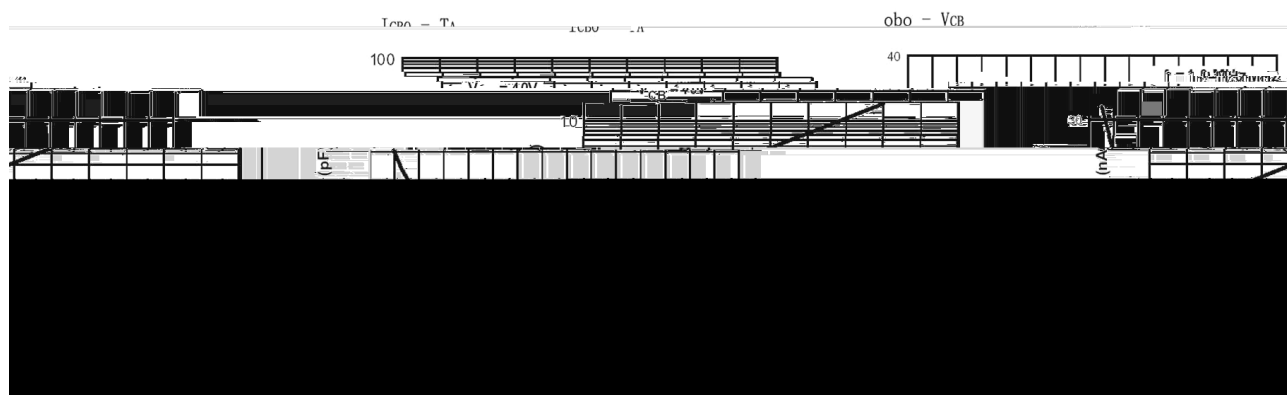
٤. ٨ ٤ / Marking

h_{FE} Classifications Symbol	16	25	40
h_{FE} Range	100 250	160 400	250 600
Marking	H6A	H6B	H6C

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	50	V
Collector to Emitter Voltage	V_{CEO}	45	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current - Continuous	I_C	500	mA
Peak Collector Current - Continuous	I_{CM}	1.0	A
Collector Power Dissipation	P_C	200	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cut-Off Current	I_{CBO}	$V_{CB}=20V$ $I_E=0$			5.0	μA
Emitter Base Cut-Off Current	I_{EBO}	$V_{EB}=5.0V$ $I_C=0$			0.1	μA
DC Current Gain	h_{FE}	$V_{CE}=1.0V$ $I_C=100mA$	100		600	
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=500mA$ $I_B=50mA$			0.7	V
Base to Emitter Voltage	V_{BE}	$V_{CE}=1.0V$ $I_C=500mA$			1.2	V

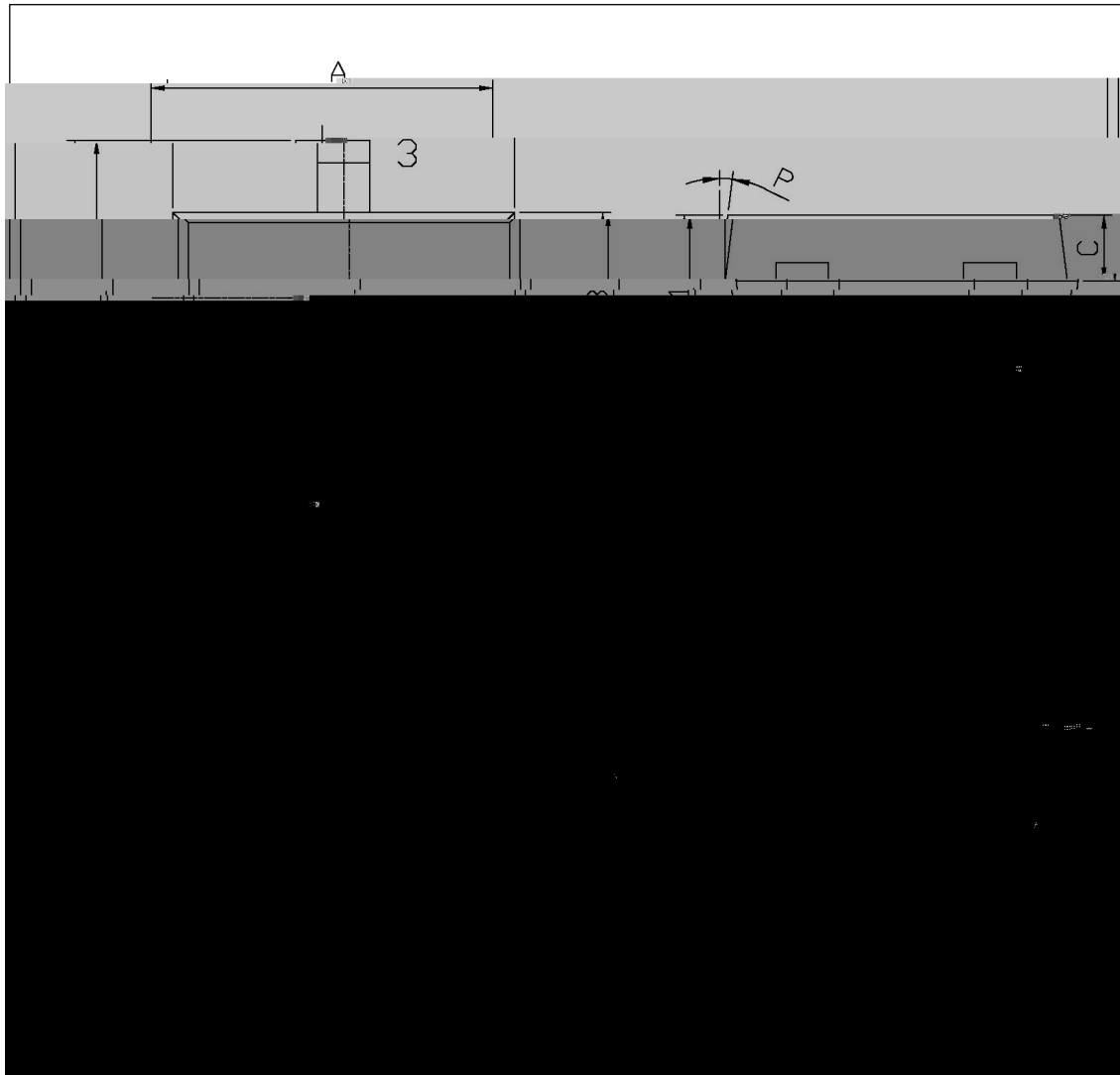
电 压 特 性 / Electrical Characteristic Curve



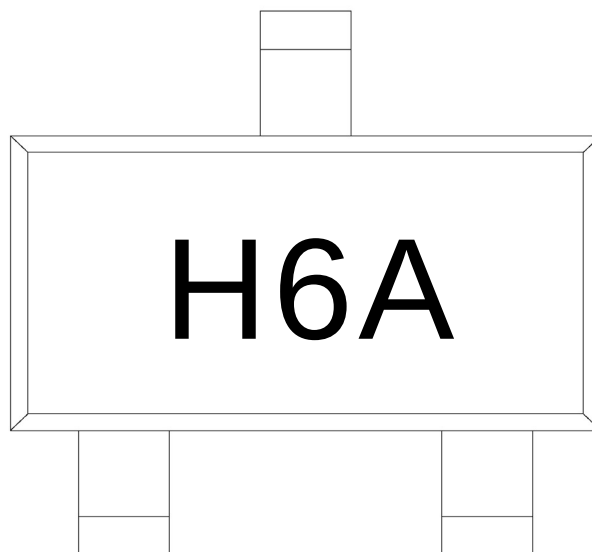
⊂ É Ò Ì f / Package Dimensions

SOT-323

单位: mm



4. 1. 1 / Marking Instructions



H

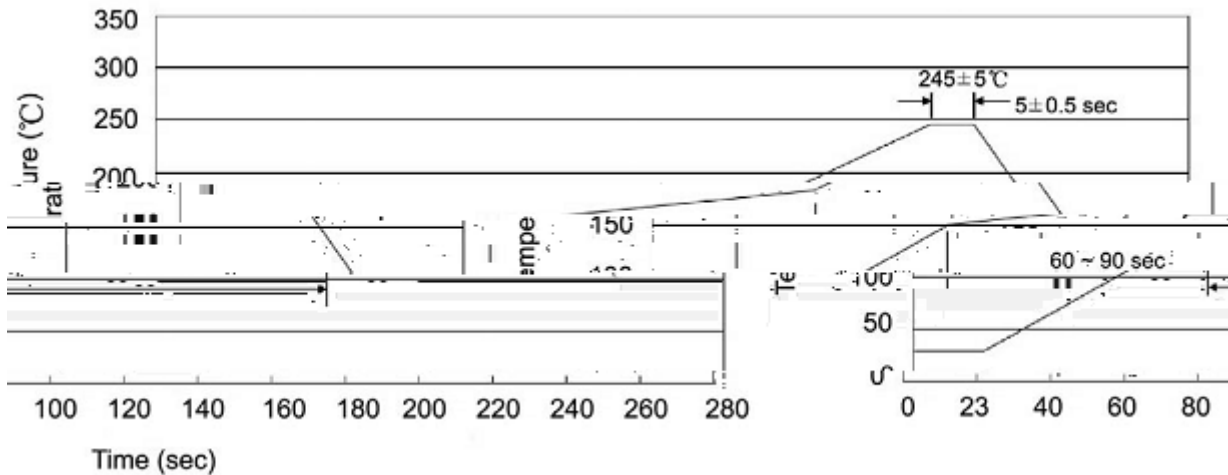
6A

Note:

H: Company Code.

6A: Product Type.

Whp shudwxuh Suriloh i ru LU Uhior z Vroghulqj+Se0l uhh,



Note:

- | | | | | | |
|---|-----|-----|----|---------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 245 | 5 | 5 | 0.5sec; | 2.Peak Temp.:245 5 , Duration:5 0.5sec. |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

Resistance to Soldering Heat Test Conditions

260 5 10 1 sec. Temp.:260±5 Time:10±1 sec

Packaging SPEC.

/ REEL

Package Type	Units					Dimension		(unit mm ³)

Notices